

# **SO310A Optical modulation Photo IC**

#### 1. Features

- Asynchronous detection
- Allowable background illuminance: 2000 lx Min.
- Light detection level: 0.4µW/mm<sup>2</sup> Typ.
- Digital output
- Light on / Dark on Selection

#### 2. Applications

#### Paper detection in office machines (Copier, Fax machines, ETC.)

• Photo sensor switches

#### 4. Description

The SO310A is an asynchronous type light modulation photo IC designed for reliable detection even under disturbance background light. A photodiode, preamplifier, comparator, voltage regulator & etc. are all integrated on a monolithic photo IC chip.

#### 3. Block Diagram





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# 5. Specifications

## **5.1 Absolute Maximum Ratings**

	•		(Ta = 25 °C)		
ITEM	Symbol	Min	Max	Unit	
Supply Voltage	VDD		6	V	
Operating temp.	Topr.	-25	60	°C	
Storage temp.	Tstg.	-40	110	°C	

### **5.2 Electro-optical Characteristics**

				DD = 5	0.0V, I	a = 2:	s°C)
	Parameter	Symbol	Condition	Min	Тур	Мах	Unit
Supply current		IDD	OUTPUT terminals shall be opened	-	-	4	mA
	Low level output voltage	V <sub>OL</sub>	I <sub>OL</sub> = 16mA	-	-	0.35	V
Output	High level output voltage	V <sub>OH</sub>	1kΩ between VDD and OUTPUT	4.9	-	-	V
	Low level circuit current	I <sub>OL</sub>	-			16	mA
"Low → ŀ	"Low $\rightarrow$ High" threshold irradiance		Light emitting diode $(\lambda p = 940 \text{ nm})$	-	0.4	2.66	$\mu$ W/mm²
"High $\rightarrow$ Low" threshold irradiance		Ee <sub>PHL</sub>	Light emitting diode $(\lambda p = 940 \text{ nm})$	-	0.4	2.8	$\mu$ W/mm²
	Hysteresis		-	0.45	-	0.95	-
B.P.F center Frequency		E <sub>HYS</sub> fc	-		200		kHz
Frequency Response		fo	-	40		300	kHz
Spect	al response sensitivity	λ	-	400	-	1100	nm
Peak wavelength		λр	-	-	850	-	nm
Boononao ti	"Low $\rightarrow$ High" propagation delay time	t <sub>PLH</sub>	VDD=5V, RL = 1 kΩ	-	-	40	μs
Response ti	"High $\rightarrow$ Low" propagation delay time	t <sub>PHL</sub>	VDD=5V, RL = 1 kΩ	-	-	20	μs
External disturbing light illuminance		-	Eep= 7.5μW/mm², λp= 940nm	2000	-	-	lx

#### (VDD = 5.0V, Ta = 25 °C)

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## 6. Application

# 6.1 Application Circuit



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# 7. Chip Information

TP LD_SEL	
Photo Diode (306 X 306um2)	1,160um
GND OUTPUT VCC	•
660um	

PAD	X[um]	Y[um]
ТР	152.3	1038.2
LD_SEL	152.3	838.2
VSS	153.1	152.3
OUTPUT	347.3	152.3
VDD	541.2	152.3

Terminal name	Description
VDD	Supply Voltage
VSS	Ground
OUTPUT	NPN open collector output terminal.
LD_SEL	Output type selection input terminal. • Open: Light ON output • Ground : Dark ON output

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